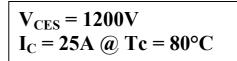
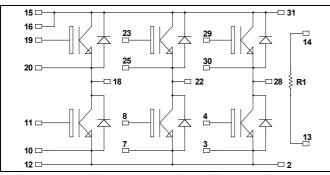
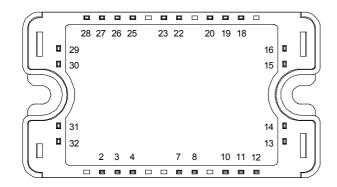


3 Phase bridge NPT IGBT Power Module





It is recommended to connect a decoupling capacitor between pins 31 & 2 to reduce switching overvoltages, if DC Power is connected between pins 15, 16 & 12. Pins 15 & 16 must be shorted together.



Application

Motor control

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- High level of integration
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

Absolute maximum ratings

| Symbol | Parameter | | Max ratings | Unit |
|-------------|---------------------------------------|---------------------|-------------|------|
| V_{CES} | Collector - Emitter Breakdown Voltage | | 1200 | V |
| $I_{\rm C}$ | Continuous Collector Current | $T_C = 25^{\circ}C$ | 40 | |
| | Continuous Conector Current | $T_C = 80^{\circ}C$ | 25 | A |
| I_{CM} | Pulsed Collector Current | $T_C = 25^{\circ}C$ | 100 | |
| V_{GE} | Gate – Emitter Voltage | | ±20 | V |
| P_{D} | Maximum Power Dissipation | $T_C = 25^{\circ}C$ | 208 | W |
| RBSOA | Reverse Bias Safe Operating Area | $T_j = 125$ °C | 50A@1150V | |

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Typ | Max | Unit |
|----------------------|--------------------------------------|-----------------------------------------|----------------|-----|-----|-----|------|
| ī | Zero Gate Voltage Collector Current | $V_{GE} = 0V$ | $T_j = 25$ °C | | | 250 | иA |
| I_{CES} | | $V_{CE} = 1200V$ | $T_j = 125$ °C | | | 500 | μΛ |
| 17 | Collector Emitter saturation Voltage | $V_{GE} = 15V$ $T_j = 25$ | $T_j = 25$ °C | 2.5 | 3.2 | 3.7 | V |
| $V_{\text{CE(sat)}}$ | Conector Emitter saturation voltage | $I_C = 25A$ | $T_j = 125$ °C | | 4.0 | | v |
| $V_{GE(th)}$ | Gate Threshold Voltage | $V_{GE} = V_{CE}$, $I_C = 1 \text{mA}$ | | 4 | | 6 | V |
| I_{GES} | Gate – Emitter Leakage Current | $V_{GE} = 20V, V_{CE} = 0V$ | | | | 400 | nA |

Dynamic Characteristics

| • | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|------------------|------------------------------|----------------------------------------------------------------------------------------------|----------------|-----|------|-----|------|
| Cies | Input Capacitance | $V_{GE} = 0V$ $V_{CE} = 25V$ | | | 1650 | | |
| C_{oes} | Output Capacitance | | | | 250 | | pF |
| C_{res} | Reverse Transfer Capacitance | f = 1MHz | | | 110 | | |
| Q_{g} | Total gate Charge | $V_{GE} = 15V$ | | | 160 | | |
| Q_{ge} | Gate – Emitter Charge | $V_{Bus} = 600V$ | | | 10 | | nC |
| Q_{gc} | Gate – Collector Charge | $I_C=25A$ | | | 70 | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive Switching (25°C) $V_{GE} = 15V$ $V_{Bus} = 600V$ $I_{C} = 25A$ $R_{G} = 22\Omega$ | | | 60 | | ns |
| $T_{\rm r}$ | Rise Time | | | | 50 | | |
| $T_{d(off)}$ | Turn-off Delay Time | | | | 305 | | |
| $T_{\rm f}$ | Fall Time | | | | 30 | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 600V$ $I_{C} = 25A$ $R_{G} = 22\Omega$ | | | 60 | | ns |
| T_{r} | Rise Time | | | | 50 | | |
| $T_{d(off)}$ | Turn-off Delay Time | | | | 346 | | |
| T_{f} | Fall Time | | | | 40 | | |
| Eon | Turn-on Switching Energy | $V_{GE} = 15V$ $V_{Bus} = 600V$ | $T_j = 125$ °C | | 3.5 | | т |
| E_{off} | Turn-off Switching Energy | $I_C = 25A$ $R_G = 22\Omega$ | $T_j = 125$ °C | | 1.5 | | mJ |

Reverse diode ratings and characteristics

| Symbol | Characteristic | Test Conditions | Test Conditions | | Тур | Max | Unit |
|-----------------|-------------------------------------------------------------|----------------------------------|------------------------|------|------|-----|------|
| V_{RRM} | Maximum Peak Repetitive Reverse Voltage | | | 1200 | | | V |
| I_{RM} | Maximum Reverse Leakage Current | V _R =1200V | $T_j = 25^{\circ}C$ | | | 100 | μA |
| 1 _{RM} | | V _R −1200 V | $T_j = 125$ °C | | | 500 | μΛ |
| I_{F} | DC Forward Current | | $Tc = 80^{\circ}C$ | | 30 | | A |
| | | $I_F = 30A$ | | | 2.6 | 3.1 | |
| $V_{\rm F}$ | Diode Forward Voltage | $I_F = 60A$ | | | 3.2 | | V |
| | | $I_F = 30A$ | $T_j = 125$ °C | | 1.8 | | |
| t | t_{rr} Reverse Recovery Time $I_{F} = 30A$ $V_{T} = 800V$ | | $T_j = 25$ °C | | 300 | | ns |
| ·rr | | $I_F = 30A$ $V_R = 800V$ | $T_{j} = 125^{\circ}C$ | | 380 | | |
| Q _{rr} | Reverse Recovery Charge | $\frac{V_R}{di/dt} = 200A/\mu s$ | $T_j = 25$ °C | | 360 | | nC |
| | | | $T_{j} = 125^{\circ}C$ | | 1700 | | 110 |



 $Temperature \ sensor \ NTC \ (\text{see application note APT0406 on www.microsemi.com for more information}). \\$

| Symbol | Characteristic | Min | Тур | Max | Unit |
|-----------------|-----------------------------|-----|------|-----|------|
| R ₂₅ | Resistance @ 25°C | | 50 | | kΩ |
| B 25/85 | $T_{25} = 298.15 \text{ K}$ | | 3952 | | K |

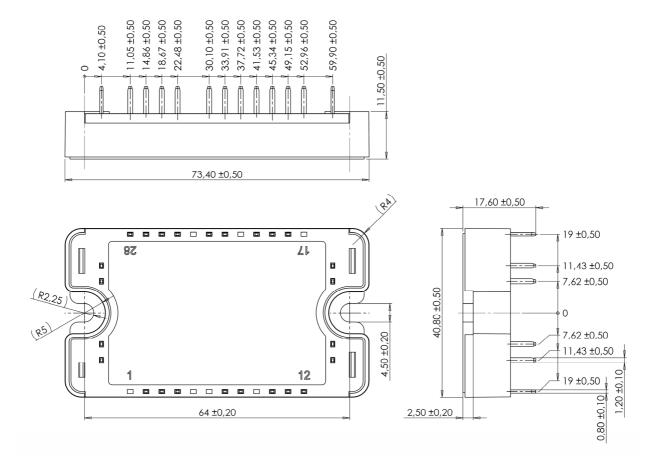
$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{75}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

Thermal and package characteristics

| Symbol | Characteristic | | | Min | Тур | Max | Unit |
|-------------------|---------------------------------------------------------------|-------------|------|-----|-----|-------|------|
| R_{thJC} | Junction to Case Thermal Resistance | | IGBT | | | 0.6 | °C/W |
| | Junction to Case Thermal Resistance | Diode | | | 1.2 | C/ VV | |
| V_{ISOL} | RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz | | 4000 | | | V | |
| T_{J} | Operating junction temperature range | | -40 | | 150 | | |
| T_{STG} | Storage Temperature Range | | -40 | | 125 | °C | |
| $T_{\rm C}$ | Operating Case Temperature | | | -40 | | 100 | |
| Torque | Mounting torque | To heatsink | M4 | 2 | | 3 | N.m |
| Wt | Package Weight | | | | | 110 | g |

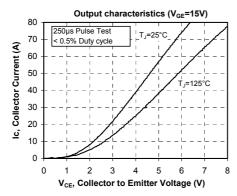
SP3 Package outline (dimensions in mm)

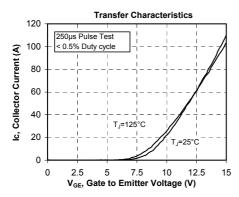


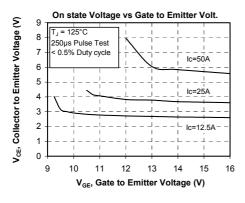
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

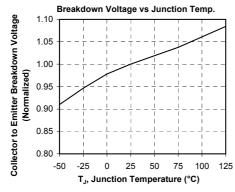


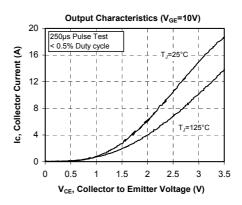
Typical Performance Curve

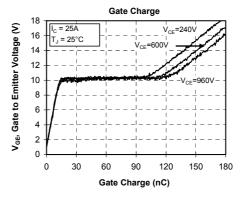


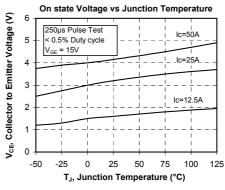


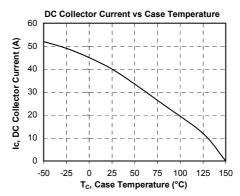




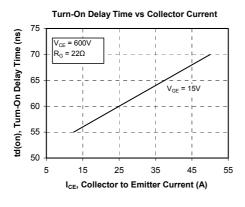


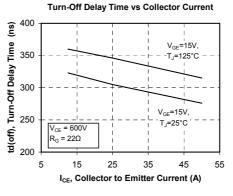


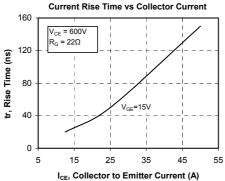


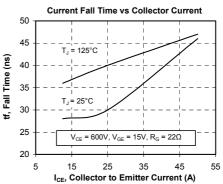


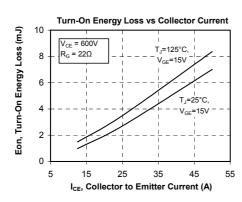


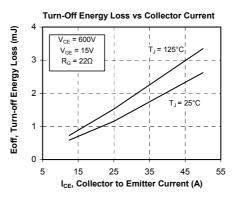


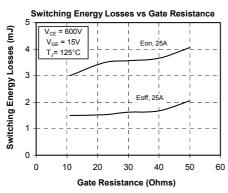


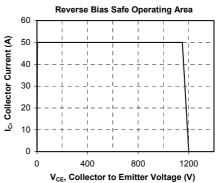




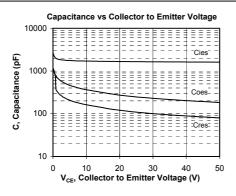


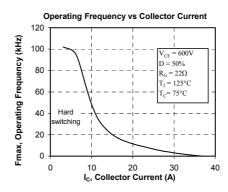


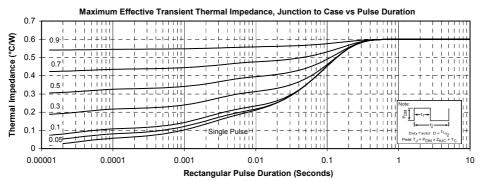












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